

Series
5.0Vdc HCMOS/TTL PCB SMD TCXO
Operating Temperature Range
40°C to +85°C
Frequency Stability
±5.0ppm Maximum

P 5.0

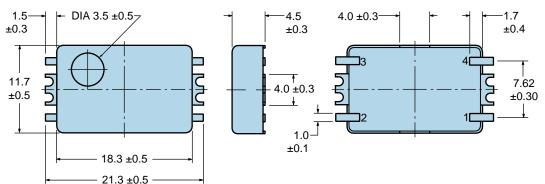
N -22.1184M
Nominal Frequency
22.1184MHz
Control Voltage
None (No Connect on Pin 1)

ELECTRICAL SPECIFICATIONS		
Nominal Frequency	22.1184MHz	
Frequency Stability	±5.0ppm Maximum (Inclusive of Operating Temperature Range)	
Frequency Stability vs. Input Voltage	±0.3ppm Maximum (±5%)	
Aging at 25°C	±1ppm/Year Maximum	
Frequency Stability vs. Load	±0.2ppm Maximum (±2pF)	
Operating Temperature Range	-40°C to +85°C	
Supply Voltage	5.0Vdc ±5%	
Input Current	20mA Maximum	
Output Voltage Logic High (Voh)	2.4Vdc Minimum w/TTL Load, Vdd-0.5Vdc Minimum w/HCMOS Load	
Output Voltage Logic Low (Vol)	0.4Vdc Maximum w/TTL Load, 0.5Vdc Maximum w/HCMOS Load	
Rise/Fall Time	10nSec Maximum (Measured at 0.4Vdc to 2.4Vdc w/TTL Load, 20% to 80% of waveform w/HCMOS Load)	
Duty Cycle	50% ±10% (Measured at 1.4Vdc w/TTL Load, at 50% of waveform w/HCMOS Load)	
Load Drive Capability	10TTL Load or 15pF HCMOS Load Maximum	
Output Logic Type	CMOS	
Control Voltage	None (No Connect on Pin 1)	
Internal Trim	±3ppm Minimum (Top of Can)	
Modulation Bandwidth	10kHz Minimum (Measured at -3dB with a Control Voltage of 2.5Vdc)	
Input Impedance	10kOhms Typical	
Phase Noise	-70dBc at 10Hz Offset, -100dBc at 100Hz Offset, -130dBc at 1kHz Offset, -140dBc at 10kHz Offset, -145dBc at 100kHz Offset (Typical Values)	
Storage Temperature Range	-40°C to +85°C	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
Fine Leak Test	MIL-STD-883, Method 1014 Condition A (Internal Crystal Only)	
Gross Leak Test	MIL-STD-883, Method 1014 Condition C (Internal Crystal Only)	
Lead Integrity	MIL-STD-883, Method 2004	
Mechanical Shock	MIL-STD-202, Method 213 Condition C	
Resistance to Soldering Heat	MIL-STD-202, Method 210	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003	
Temperature Cycling	MIL-STD-883, Method 1010	
Vibration	MIL-STD-883, Method 2007 Condition A	



### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**

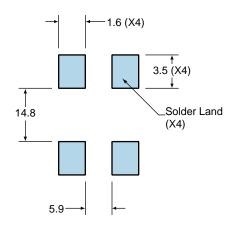


PIN	CONNECTION
1	No Connect
2	Ground
3	Output
4	Supply Voltage

LINE	MARKING
1	ECLIPTEK
2	<b>22.118M</b> <i>M=MHz</i>
3	XXYZZ XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year

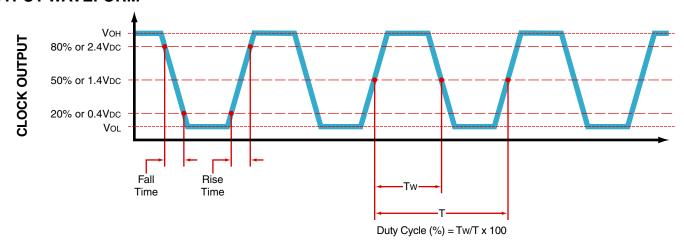
#### **Suggested Solder Pad Layout**

All Dimensions in Millimeters



All Tolerances are ±0.1

#### **OUTPUT WAVEFORM**





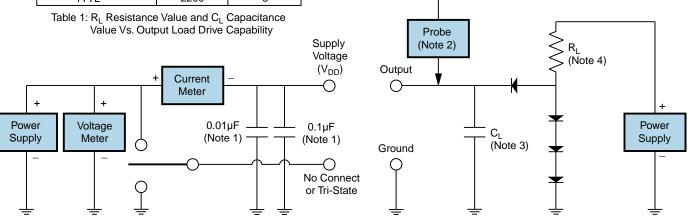
Frequency

Counter

Oscilloscope

### **Test Circuit for TTL Output**

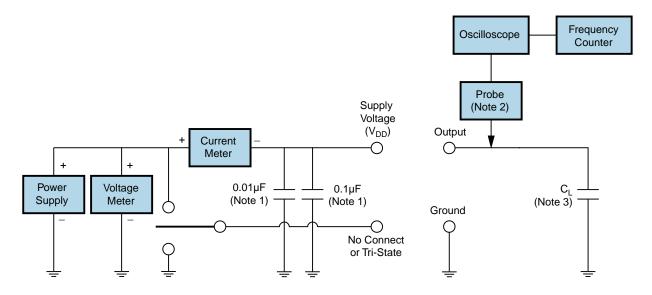
Output Load Drive Capability	R <sub>L</sub> Value (Ohms)	C <sub>L</sub> Value (pF)
10TTL	390	15
5TTL	780	15
2TTL	1100	6
10LSTTL	2000	15
1TTL	2200	3



- Note 1: An external  $0.1\mu F$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu F$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value  $C_L$  includes sum of all probe and fixture capacitance.
- Note 4: Resistance value R<sub>L</sub> is shown in Table 1. See applicable specification sheet for 'Load Drive Capability'.
- Note 5: All diodes are MMBD7000, MMBD914, or equivalent.



### **Test Circuit for CMOS Output**



Note 1: An external  $0.1\mu F$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu F$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.



## **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 240°C

T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	N/A
- Temperature Typical (T <sub>S</sub> TYP)	150°C
- Temperature Maximum (T <sub>s</sub> MAX)	N/A
- Time (t <sub>s</sub> MIN)	60 - 120 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	240°C Maximum
Target Peak Temperature (T <sub>P</sub> Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

### **Low Temperature Manual Soldering**

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.